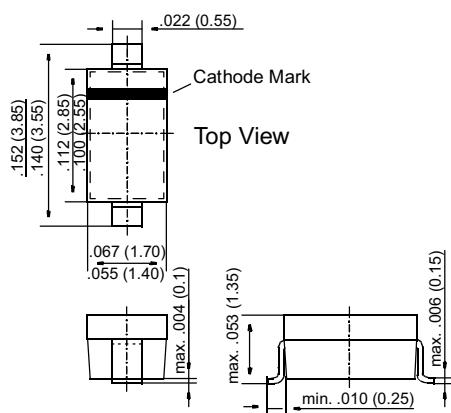


# BAV19W THRU BAV21W

## Small Signal Diodes

### SOD-123



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Silicon Epitaxial Planar Diodes
- ◆ For general purpose
- ◆ These diodes are also available in other case styles including: the DO-35 case with the type designations BAV19 to BAV21, the MiniMELF case with the type designations BAV100 to BAV103 and the SOT-23 case with the type designation BAS19 - BAS21.



### MECHANICAL DATA

Case: SOD-123 Plastic Case

Weight: approx. 0.01 g

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

		Symbol	Value	Unit
Reverse Voltage	BAV19W BAV20W BAV21W	$V_R$	120 200 250	V
Forward DC Current at $T_{amb} = 25 \text{ }^{\circ}\text{C}$		$I_F$	250 <sup>1)</sup>	mA
Rectified Current (Average) Half Wave Rectification with Resist. Load at $T_{amb} = 25 \text{ }^{\circ}\text{C}$ and $f \geq 50 \text{ Hz}$		$I_0$	200 <sup>1)</sup>	mA
Repetitive Peak Forward Current at $f \geq 50 \text{ Hz}$ , $\Theta = 180 \text{ }^{\circ}$ , $T_{amb} = 25 \text{ }^{\circ}\text{C}$		$I_{FRM}$	625 <sup>1)</sup>	mA
Surge Forward Current at $t < 1 \text{ s}$ , $T_j = 25 \text{ }^{\circ}\text{C}$		$I_{FSM}$	1	A
Power Dissipation at $T_{amb} = 25 \text{ }^{\circ}\text{C}$		$P_{tot}$	410 <sup>1)</sup>	mW
Junction Temperature		$T_j$	150 <sup>1)</sup>	°C
Storage Temperature Range		$T_S$	-65 to +150 <sup>1)</sup>	°C

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature (SOD-123)

# BAV19W THRU BAV21W

## ELECTRICAL CHARACTERISTICS

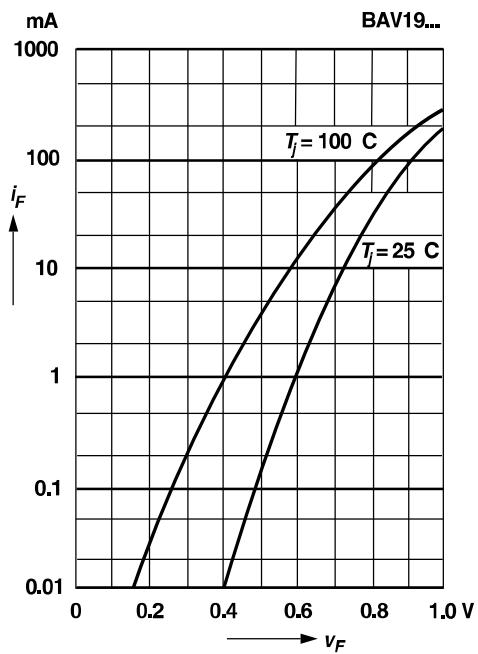
Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
Forward voltage at $I_F = 100 \text{ mA}$	$V_F$	—	—	1	V
Leakage Current at $V_R = 100 \text{ V}$ $\text{BAV19W}$	$I_R$	—	—	100	nA
at $V_R = 100 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV19W}$	$I_R$	—	—	15	$\mu\text{A}$
at $V_R = 150 \text{ V}$ $\text{BAV20W}$	$I_R$	—	—	100	nA
at $V_R = 150 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV20W}$	$I_R$	—	—	15	$\mu\text{A}$
at $V_R = 200 \text{ V}$ $\text{BAV21W}$	$I_R$	—	—	100	nA
at $V_R = 200 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV21W}$	$I_R$	—	—	15	$\mu\text{A}$
Dynamic Forward Resistance at $I_F = 10 \text{ mA}$	$r_f$	—	5	—	$\Omega$
Capacitance at $V_R = 0, f = 1 \text{ MHz}$	$C_{tot}$	—	1.5	—	pF
Reverse Recovery Time from $I_F = 30 \text{ mA}$ through $I_R = 30 \text{ mA}$ to $I_R = 3 \text{ mA}; R_L = 100 \Omega$	$t_{rr}$	—	—	50	ns
Thermal Resistance Junction to Ambient Air	$R_{thJA}$	—	—	375 <sup>1)</sup>	K/W

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature

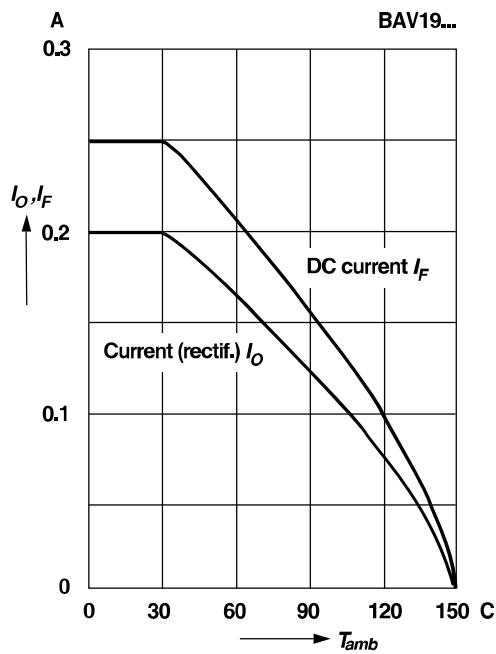
## RATINGS AND CHARACTERISTIC CURVES BAV19W THRU BAV21W

**Forward characteristics**



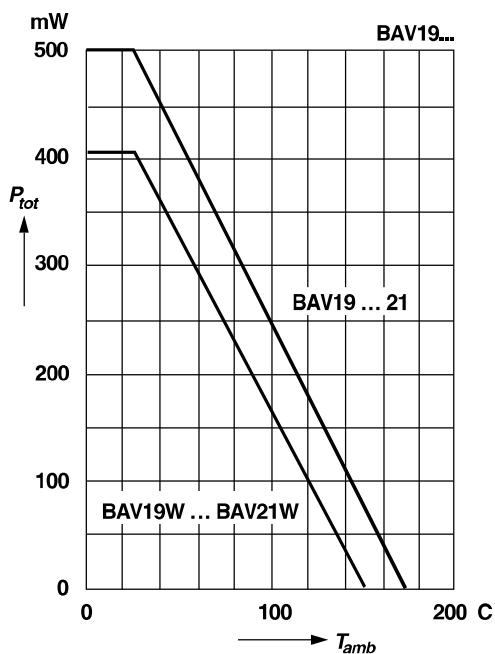
**Admissible forward current versus ambient temperature**

For conditions, see footnote in table  
"Absolute Maximum Ratings"

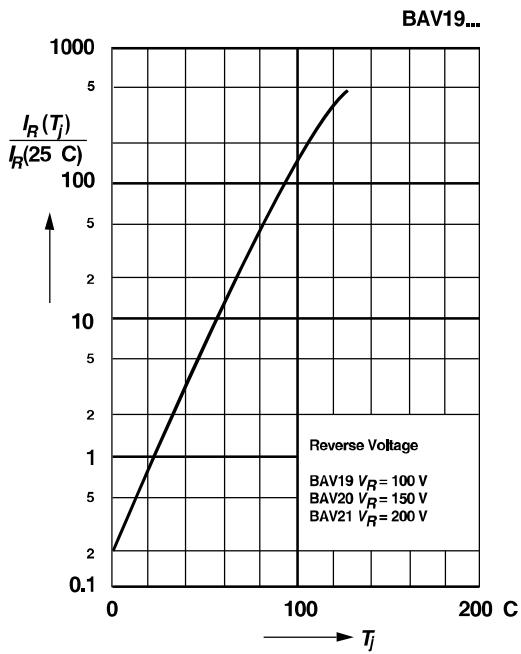


**Admissible power dissipation versus ambient temperature**

For conditions, see footnote in table  
"Absolute Maximum Ratings"



**Leakage current versus junction temperature**

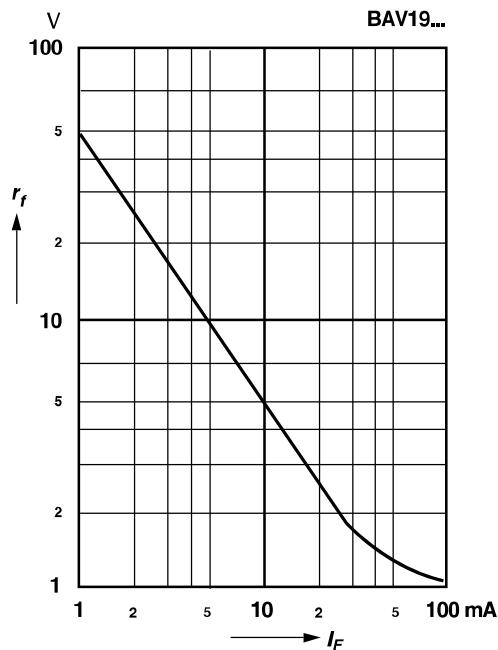


---

## RATINGS AND CHARACTERISTIC CURVES BAV19W THRU BAV21W

---

Dynamic forward resistance  
versus forward current



Capacitance  
versus reverse voltage

